

Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of Automotive Applications.

Features

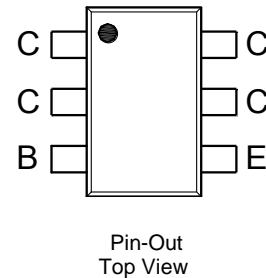
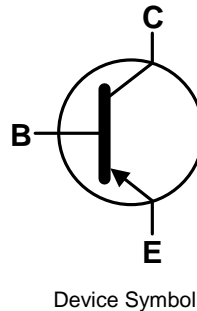
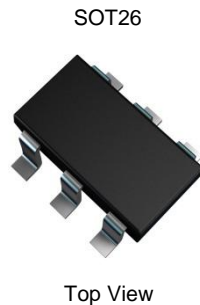
- $BV_{CEO} > -20V$
- $I_C = -2.5A$ Continuous Collector Current
- $I_{CM} = -6A$ Peak Pulse Current
- $R_{CE(SAT)} = 96m\Omega$ for a Low Equivalent On-Resistance
- Low Saturation Voltage (-220mV Max @ -1A)
- h_{FE} Characterized up to -6A for High Current Gain Hold-Up
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

Mechanical Data

- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 [Ⓔ]
- Weight: 0.015 grams (Approximate)

Applications

- DC-DC Converters
- Power Management Functions
- Power Switches
- Motor Control

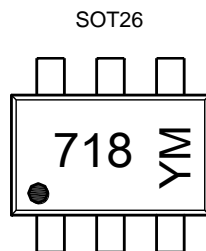


Ordering Information (Note 5)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
ZXT10P20DE6QTA	Automotive	718	7	8	3,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to <https://www.diodes.com/quality/>.
 5. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



718 = Product Type Marking Code
 YM = Date Code Marking
 Y or \bar{Y} = Year (ex: F = 2018)
 M or \bar{M} = Month (ex: 9 = September)

Date Code Key

Year	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	
Code	F	G	H	I	J	K	L	M	N	O	P	
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	-20	V
Collector-Emitter Voltage	V _{CEO}	-20	V
Emitter-Base Voltage	V _{EBO}	-7	V
Base Current	I _B	-500	mA
Continuous Collector Current	I _C	-2.5	A
Peak Pulse Collector Current	I _{CM}	-6	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

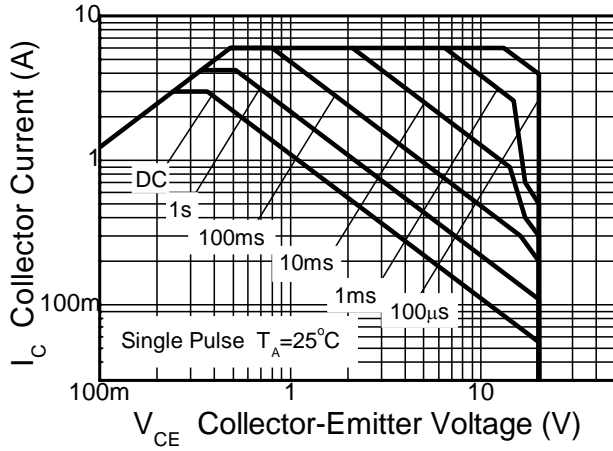
Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	1.1	W
		8.8	
Linear Derating Factor		1.7	mW/°C
		13.6	
Thermal Resistance, Junction to Ambient	R _{θJA}	113	°C/W
		73	
Thermal Resistance, Junction to Leads	R _{θJL}	30.01	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 9)

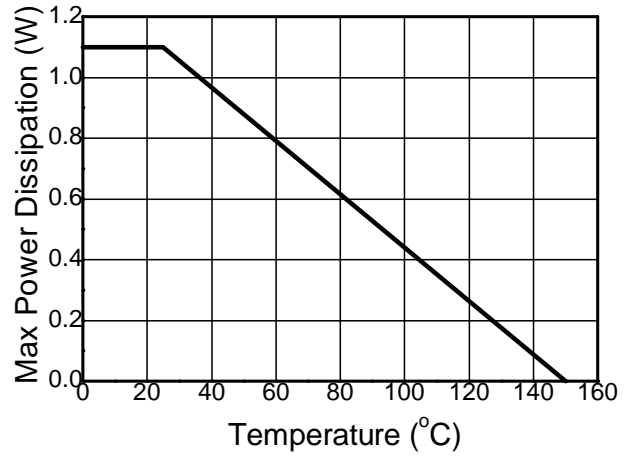
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
6. For a device mounted with collector leads on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 7. Same as Note 6, except the device is measured at t ≤ 5secs.
 8. Thermal resistance from junction to solder-point (at the end of the collector leads).
 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

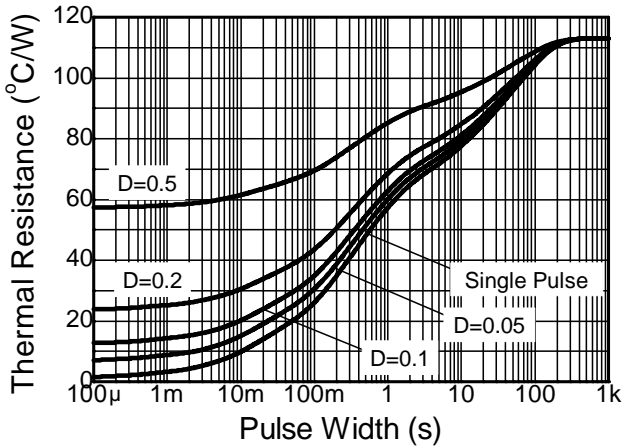
Thermal Characteristics and Derating Information



Safe Operating Area



Derating Curve



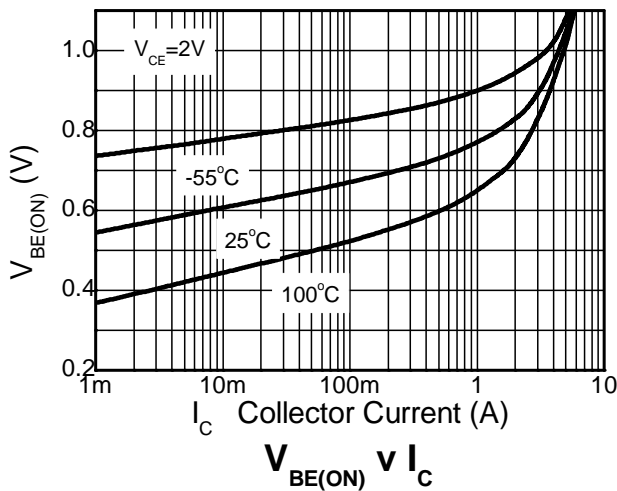
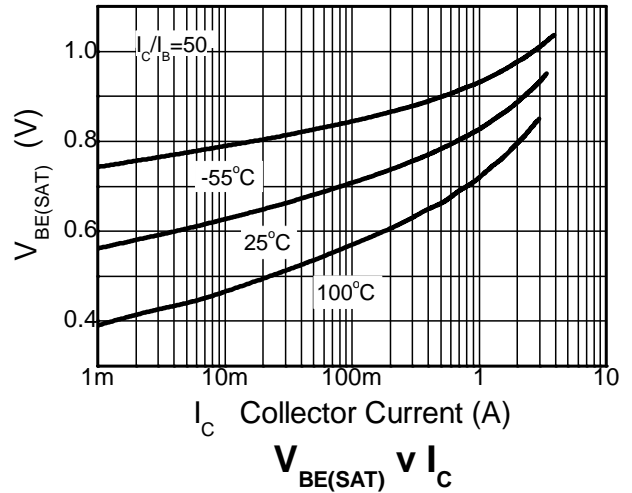
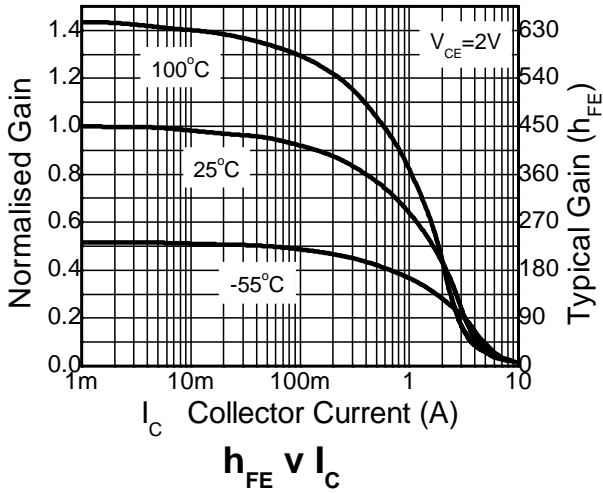
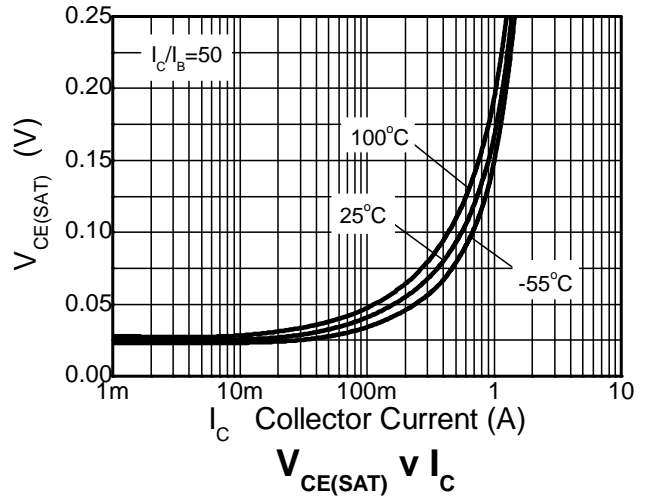
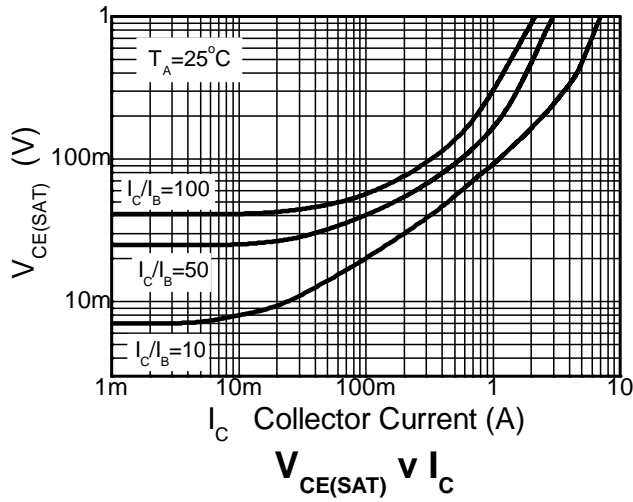
Transient Thermal Impedance

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CB0}	-20	-65	—	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	-20	-53	—	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.8	—	V	I _E = -100μA
Collector-Base Cutoff Current	I _{CB0}	—	<1	-100	nA	V _{CB} = -15V
Emitter Cutoff Current	I _{EBO}	—	<1	-100	nA	V _{EB} = -5V
Collector-Emitter Cutoff Current	I _{CES}	—	<1	-100	nA	V _{CES} = -15V
ON CHARACTERISTICS (Note 10)						
DC Current Gain	h _{FE}	300	475	—	—	I _C = -10mA, V _{CE} = -2V
		300	450	—	—	I _C = -0.1A, V _{CE} = -2V
		150	230	—	—	I _C = -2A, V _{CE} = -2V
		15	30	—	—	I _C = -6A, V _{CE} = -2V
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	—	-19	-30	mV	I _C = -0.1A, I _B = -10mA
		—	-170	-220		I _C = -1A, I _B = -20mA
		—	-190	-250		I _C = -1.5A, I _B = -50mA
		—	-240	-350		I _C = -2.5A, I _B = -150mA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	—	-0.97	-1.05	V	I _C = -2.5A, I _B = -150mA
Base-Emitter Turn-On Voltage	V _{BE(ON)}	—	-0.85	-0.95	V	I _C = -2.5A, V _{CE} = -2V
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	f _T	150	180	—	MHz	V _{CE} = -10V, I _C = -50mA, f = 100MHz
Output Capacitance	C _{OBO}	—	21	30	pF	V _{CB} = -10V, f = 1MHz
Turn-On Time	t _(ON)	—	40	—	ns	V _{CC} = -10V, I _C = -1A
Turn-Off Time	t _(OFF)	—	670	—	ns	I _{B1} = -I _{B2} = -20mA

Note: 10. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

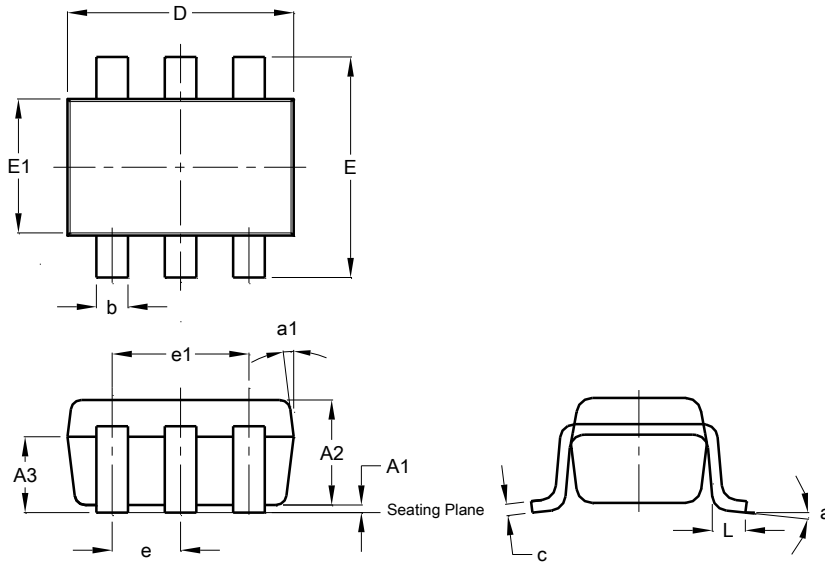
Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT26

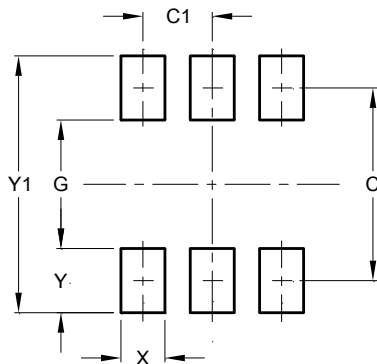


SOT26			
Dim	Min	Max	Typ
A1	0.013	0.10	0.05
A2	1.00	1.30	1.10
A3	0.70	0.80	0.75
b	0.35	0.50	0.38
c	0.10	0.20	0.15
D	2.90	3.10	3.00
e	-	-	0.95
e1	-	-	1.90
E	2.70	3.00	2.80
E1	1.50	1.70	1.60
L	0.35	0.55	0.40
a	-	-	8°
a1	-	-	7°
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT26



Dimensions	Value (in mm)
C	2.40
C1	0.95
G	1.60
X	0.55
Y	0.80
Y1	3.20

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